ligh Power Amplifier **RFE-24M30M1K7X+**

27 MHz SMA to N-Type 1700W Mini-Circuits 500

THE BIG DEAL

- High output power, 1700W
- 27MHz ISM band
- Power gain of 26 dB with 5W input drive level
- Suitable for CW and pulsed signals
- High gain, 26 dB typical

- 80% efficiency
- Rugged construction
- Built-in monitoring for temperature and current
- Built-in emergency switch-off
- Water cooled



Generic photo used for illustration purposes only

RFE-24M30M1K7X+

VW3194

SMA-Input / N-type-Output

Model No.

Case Style

Connectors

APPLICATIONS

The RFE-24M30M1K7X+ amplifier module can be used as a building block in any single or multi-channel system for high power RF Energy applications such as:

- Industrial heating and Materials processing
 - **RF-excited** lasers
- Food processing (heating, tempering, pasteurization) Microwave-assisted chemistry
- Plasma generation and Plasma surface treatment
- Disinfection

- Chemistry
- Medical (heating, hyperthermia, and ablation) •
- Semiconductor RF generators

+RoHS Compliant The +Suffix identifies RoHS Complianc our website for methodologies and qualificatio

PRODUCT OVERVIEW

The RFE-24M30M1K7X+ is a new generation light weight solid state connectorized high-power amplifier module which can be used in a wide range of industrial, scientific and medical applications in the 27 MHz ISM band. The RFE-24M30M1K7X+ uses the latest generation semiconductor technology and provides unsurpassed output power, efficiency and ruggedness. The amplifier is capable of amplifying signals (CW & pulsed) in excess of 1700W. A temperature compensated gate bias circuit is provided. Built-in circuitry provides temperature monitoring and current monitoring. An on-board emergency switch can be triggered with an external TTL signal to switch off the power amplifier in the case of too much reflected or dissipated power.

All interfaces to the outside world are accessible through a convenient USB-C connector. The amplifier has a SMA-connector on the input and an N-connector on the output. The mounting base plate has an integrated water channel to provide cooling under difficult operating conditions, such as high mismatch or high dissipated power. Convenient rotatable push-to-connect tube fittings allow for easy and reliable water cooling connections. Integrated transformer cooling ensures a long amplifier lifetime. The amplifier is supplied with a robust shield. M5 screw holes are provided to mount the amplifier to a chassis in larger systems. Easy screw-on power supply connections are provided outside the shield.

KEY FEATURES

Feature	Advantages
High CW Power	Supports high power applications for a wide range of industrial, scientific and medical applications in the 27 MHz ISM band.
High Gain	A typical gain of 26 dB at P3dB allows the RFE-24M30M1K7X+ to be driven to full output power with only 5 Watts of input power.
High Efficiency	The RFE-24M30M1K7X+ uses high efficiency state of the art highly rugged semiconductor technology.
Control and Monitoring Feature	The power amplifier has an integrated temperature compensated gate bias and built-in temperature and current moni- toring feature. Monitoring outputs are differential. A TLL level PA enable pin is provided. To avoid any damage, a fast emergency shutoff is provided to shut down the power amplifier in a high dissipation or high reflected power situation.
Small and lightweight	The compact amplifier design (176mm x 96mm x 85mm) is lightweight (1202 grams) which makes it suitable for integra- tion in high power systems that require multiple amplifiers.
Cooling	Convenient rotatable push-to-connect tube fittings allow for easy connection of the water cooling.



High Power Amplifier RFE-24M30M1K7X+

1700W 27 MHz SMA to N-Type 50Ω Mini-Circuits

ELECTRICAL SPECIFICATIONS AT 27.12 MHz, T_{WATER}=+25°C, V_{DS}=65V, 50Ω SYSTEM

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Frequency Range	f		27.12		MHz	
Operating Voltage	V _{DS}		50	65	66	V
Input Power	P _{IN}		-	-	10	Watts
			-	-	40	dBm
Output Power at 1dB compression	P_{1dB}		1200	1660	-	Watts
			60.8	62.2	-	dBm
Output Power at 3dB compression	P _{3dB}		1500	1891	-	Watts
			61.8	62.7	-	dBm
Power Gain	G _P	P3dB	22	25	-	dB
Efficiency	η	P3dB	70	80	-	%
Input VSWR	IRL	P3dB	-	-	1.92	:1
Harmonics (H2)	H2		-	-45	-	dBc
Harmonics (H3)	H3		-	-30	-	dBc
Current Monitor Out	СМО	Connector J1, A2=CDO+, A3=CDO-, P3dB at 27.12 MHz	-	2.5	-	V
Temperature Monitor Out	ТМО	Connector J1, A10=TDO-, A11=TDO+, P3dB at 27.12 MHz	-	1.1	-	V
Power Supply Shut-Off	V _{DSSQ}	Enable (TTL low) / Disable (TTL high) on Pin A6 of Connector J1				
PA Enable	PA _{EN}	Enable (TTL high) / Disable (TTL low) on Pin A7 of Connector J1				

1. All power measurements are performed while using a Mini-Circuits NLP-30+ Low Pass Filter in front of the power sensors.

2. +VDS and Ground are connected at the bottom of the amplifier using M5 screws.
3. AThis amplifier cannot be run without water cooling. A minimum water flow rate of 4 Gallons/minute (approx. 15 liter/minute) and pressure of 10psi (69 kPa) is recommended.

MAXIMUM RATINGS¹

Parameter	Ratings
Operating Water Temperature	0°C to +65°C
Storage Temperature	-20°C to +85°C
DC Voltage (V _{DS})	66V
Input RF Power (no damage)	+40 dBm

1.Specifications apply to CW signals only. Permanent damage may occur if any of these limits are exceeded.



FUNCTIONAL BLOCK DIAGRAM



CONTROL INTERFACE PIN-OUT AND FUNCTIONALITY (J1, MULTI-PIN USB-C CONNECTOR)

Pin Number	Label	Functionality
A1	GND	Ground
A2	CDO+	Current Differential Output+
A3	CDO-	Current Differential Output-
A4	GND	Ground
A5	GND	Ground
A6	V _{DSSO}	Power Supply Shut Off
A7	PA _{EN}	PA Enable
A8	GND	Ground
A9	GND	Ground
A10	TDO-	Temperature Differential Output-
A11	TDO+	Temperature Differential Output+
A12	GND	Ground
B1-B12	Do not connect	Reserved pin for manufacturer

PIN CONFIGURATION USB-C CONNECTOR



COAXIAL SOLID-STATE High Power Amplifier RFE-24M30M1K7X+

Mini-Circuits 50Ω 1700W 27 MHz SMA to N-Type

OUTLINE DRAWING



Weight: 1202 grams; Dimensions are in inches (mm). Tolerances: 2 Pl.± ; 3 Pl. ±

High Power Amplifier **RFE-24M30M1K7X+**

Mini-Circuits

50Ω 1700W 27 MHz SMA to N-Type

TYPICAL PERFORMANCE DATA AT 27 MHz (T_{WATER} = +25°C, V_{DS} = 65V, 50 Ω SYSTEM)



TYPICAL PERFORMANCE DATA AT 27 MHz ACROSS DIFFERENT OPERATING WATER TEMPERATURE $(V_{DS} = 65V, 50\Omega \text{ SYSTEM})$



Mini-Circuits

COAXIAL SOLID-STATE High Power Amplifier **RFE-24M30M1K7X+**

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50Ω 1700W 27 MHz SMA to N-Type

TYPICAL PERFORMANCE DATA AT 27 MHz ACROSS DIFFERENT VOLTAGES (T_{WATER}= +25°C, 50Ω SYSTEM)





— Drain Efficiency 50 V — Drain Efficiency 55 V — Drain Efficiency 60 V — Drain Efficiency 65 V

TYPICAL PERFORMANCE DATA AT 27 MHz (T_{water} = +25°C, V_{DS} = 65V, 50 Ω SYSTEM)









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COAXIAL SOLID-STATE High Power Amplifier RFE-24M30M1K7X+ 50Ω 1700W 27 MHz SMA to N-Type

TYPICAL PERFORMANCE DATA AT 27 MHz ACROSS DIFFERENT OPERATING WATER TEMPERATURE (V_{DS} = 65V, 50 Ω SYSTEM)



TYPICAL PERFORMANCE DATA AT 27 MHz ACROSS DIFFERENT VOLTAGES (T_{WATER}= +25°C, 50Ω SYSTEM)



Power Gain (dB) and Drain Efficiency(%) vs Pout(dBm) Power Gain (dB) Drain Efficiency(%) P_{OUT}(dBm) -Power Gain 50 V -Power Gain 55 V ----Power Gain 60 V -Power Gain 65 V — Drain Efficiency 50 V — Drain Efficiency 55 V — Drain Efficiency 60 V — Drain Efficiency 65 V

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COAXIAL SOLID-STATE High Power Amplifier RFE-24M30M1K7X+ 50Ω 1700W 27 MHz SMA to N-Type





COAXIAL SOLID-STATE High Power Amplifier RFE-24M30M1K7X+ 50Ω 1700W 27 MHz SMA to N-Type

TYPICAL PERFORMANCE DATA ACROSS FREQUENCY (T_{WATER}= +25°C, V_{DS} = 65V, 50 Ω SYSTEM)





High Power Amplifier RFE-24M30M1K7X+

Mini-Circuits 50Ω 1700W 27 MHz SMA to N-Type

AMPLIFIER INTERFACES AND SUGGESTED MATING HARDWARE*

J1 - CONN RCP USB3.1 TYPEC 24P SMD RA equivalent to Molex P/N 1054500101
+65V Supply Voltage Connector, M5 Ground Connection,M5 Tightening Torque 1.7 N-m (15 in-lbs) Mating Hardware*: M5 screw equivalent to McMaster P/N 92095A308 Belville washer equivalent to McMaster P/N 90895A027 Ring Terminal equivalent to McMaster P/N 7113K29
J3: SMA Connector Receptacle, Female Socket 500hm equivalent toTE Connectivity AMP Connectors, P/N 1052566-1
J4 - N Type Connector Receptacle, Female Socket 500hm equivalent to Amphenol P/N 172195

*Mating hardware not included with amplifier. Similar mating hardware available from other manufactures.

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SAFETY INSTRUCTIONS.

WARNING: FAILURE TO FOLLOW THESE INSTRUCTIONS MAY RESULT IN BODILY INJURY, DEATH, OR PROPERTY DAMAGE. For your own safety, this section provides instructions for avoiding potential dangers when using this product.

QUALIFIED PERSONNEL

This product should be operated by qualified personnel only. Qualified personnel are individuals who are familiar with the operation of the product and the hazards involved with such operation.

DAMAGED OR MISSING HARDWARE

Do not operate the product if there is physical damage or hardware is missing.

MAXIMUM RATINGS

The maximum ratings in this data sheet should never be exceeded. Stress above one or more maximum ratings may cause permanent damage to the product and may permanently and irreversibly affect the quality and reliability of the product, which may increase the risk of bodily injury, death, or property damage.

HAZARDOUS RF VOLTAGES

The RF voltages inside the product and on the center pin of the RF output connector can be hazardous. Contact with the internal components of the product or the center pin of the RF output connector may lead to burns or electrical shock. Disconnect power before removing the protective cover from the product will void the express warranty specified in Mini-Circuits Standard Terms.

To reduce the risks presented by these hazards:

- 1. never operate the product without its protective cover,
- 2. always connect the RF output connector to a load before the power source is applied to the product, and
- 3. always place the product in a non-operating condition before disconnecting or connecting the load to the RF output connector.

COOLING

RF Power amplifiers always need proper cooling. Failure to properly cool the product may increase the risk of bodily injury, death, or damage to property or the product.

Some products contain water cooling systems to help cool down the product. If this data sheet indicates that the product contains a water cooling system, proper waterflow as specified in this data sheet is required to keep the temperature of the product within the temperature range that is specified in this data sheet.

Some products also contain built-in protection circuitry designed to shut-off the amplifier at excessive high temperatures or at other excessive operating conditions. Even if this data sheet indicates that the product contains protective circuitry, such protective circuitry is not a substitute for proper handling in accordance with these instructions. Accordingly, do not rely on the protective circuitry to prevent injury or damage to property or the product.

MAINTENANCE CAUTION

Maintenance or repair of the product must only be performed by qualified personnel when the product is in a non-operating condition and disconnected from its power source. Note that performance of maintenance or repairs to the product will void the express warranty specified in Mini-Circuits Standard Terms.

ENVIRONMENTAL CONDITIONS

Unless otherwise stated in this data sheet, this product is designed to be operated under the environmental conditions set forth in this data sheet, as well as the following conditions:

- Indoor use only
- Temperature of 5°C to 40°C (non-condensing)

WARNING SIGNS

In addition to being qualified before operating the product, pay attention to all warning signs and danger symbols. Failure to heed warnings signs and danger symbols, or to follow their associated instructions, may result in bodily injury, death, or property damage.

NOTES

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/terms/viewterm.html

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